

SN54AHC16541, SN74AHC16541 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCLS332F – MARCH 1996 – REVISED JANUARY 2000

- **Members of the Texas Instruments Widebus™ Family**
- **EPIC™ (Enhanced-Performance Implanted CMOS) Process**
- **Operating Range 2-V to 5.5-V V_{CC}**
- **Distributed V_{CC} and GND Pins Minimize High-Speed Switching Noise**
- **Flow-Through Architecture Optimizes PCB Layout**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), and Thin Very Small-Outline (DGV) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings**

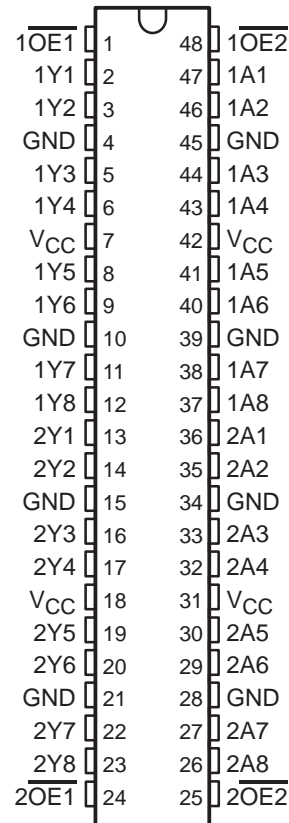
description

The 'AHC16541 devices are noninverting 16-bit buffers composed of two 8-bit sections with separate output-enable signals. For either 8-bit buffer section, the two output-enable ($\overline{1OE1}$ and $\overline{1OE2}$ or $\overline{2OE1}$ and $\overline{2OE2}$) inputs must be low for the corresponding Y outputs to be active. If either output-enable input is high, the outputs of that 8-bit buffer section are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHC16541 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74AHC16541 is characterized for operation from -40°C to 85°C .

SN54AHC16541 . . . WD PACKAGE
SN74AHC16541 . . . DGG, DGV, OR DL PACKAGE
(TOP VIEW)



FUNCTION TABLE
(each 8-bit buffer/driver)

INPUTS			OUTPUT Y
$\overline{OE1}$	$\overline{OE2}$	A	
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z



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**TEXAS
INSTRUMENTS**

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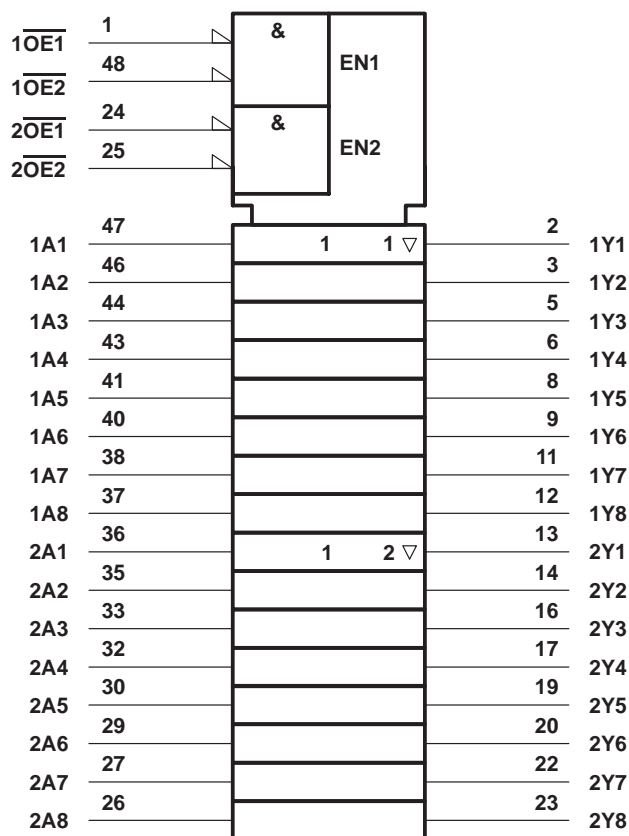
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16-BIT BUFFERS/DRIVERS

WITH 3-STATE OUTPUTS

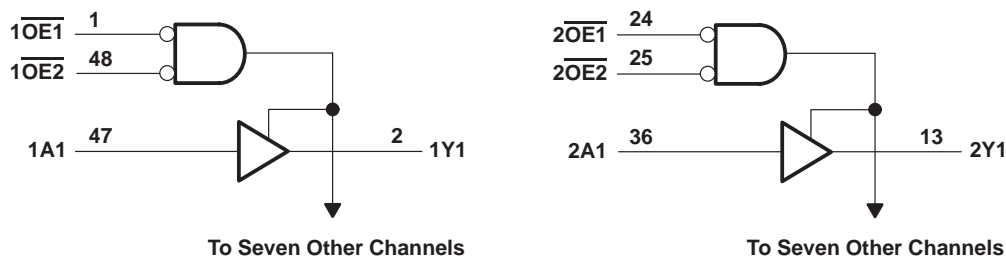
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logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



Supply voltage range, V_{CC}	-0.5 V to 7 V
Input voltage range, V_I (see Note 1)	-0.5 V to 7 V
Output voltage range, V_O (see Note 1)	-0.5 V to $V_{CC} + 0.5$ V
Input clamp current, I_{IK} ($V_I < 0$)	-20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	± 20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	± 25 mA
Continuous current through each V_{CC} or GND	± 75 mA
Package thermal impedance, θ_{JA} (see Note 2):		
DGG package	70°C/W
DGV package	58°C/W
DL package	63°C/W

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The package thermal impedance is calculated in accordance with JEDEC 51.

			SN54AHC16541		SN74AHC16541		UNIT
			MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage		2	5.5	2	5.5	V
V _{IH}	High-level input voltage	V _{CC} = 2 V	1.5		1.5		V
		V _{CC} = 3 V	2.1		2.1		
		V _{CC} = 5.5 V	3.85		3.85		
V _{IL}	Low-level input voltage	V _{CC} = 2 V		0.5		0.5	V
		V _{CC} = 3 V		0.9		0.9	
		V _{CC} = 5.5 V		1.65		1.65	
V _I	Input voltage		0	5.5	0	5.5	V
V _O	Output voltage		0	V _{CC}	0	V _{CC}	V
I _{OH}	High-level output current	V _{CC} = 2 V		−50		−50	μA
		V _{CC} = 3.3 V ± 0.3 V		−4		−4	mA
		V _{CC} = 5 V ± 0.5 V		−8		−8	
I _{OL}	Low-level output current	V _{CC} = 2 V		50		50	μA
		V _{CC} = 3.3 V ± 0.3 V		4		4	mA
		V _{CC} = 5 V ± 0.5 V		8		8	
Δt/Δv	Input transition rise or fall rate	V _{CC} = 3.3 V ± 0.3 V		100		100	ns/V
		V _{CC} = 5 V ± 0.5 V		20		20	
T _A	Operating free-air temperature		−55	125	−40	85	°C

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C			SN54AHC16541		SN74AHC16541		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V _{OH}	I _{OH} = –50 µA	2 V	1.9	2		1.9		1.9		V
		3 V	2.9	3		2.9		2.9		
		4.5 V	4.4	4.5		4.4		4.4		
	I _{OH} = –4 mA	3 V	2.58			2.48		2.48		
	I _{OH} = –8 mA	4.5 V	3.94			3.8		3.8		
V _{OL}	I _{OL} = 50 µA	2 V			0.1		0.1		0.1	V
		3 V			0.1		0.1		0.1	
		4.5 V			0.1		0.1		0.1	
	I _{OL} = 4 mA	3 V			0.36		0.5		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.5		0.44	
I _I	V _I = V _{CC} or GND	0 V to 5.5 V			±0.1		±1*		±1	µA
I _{OZ}	V _O = V _{CC} or GND, V _I ($\overline{\text{OE}}$) = V _{IL} or V _{IH}	5.5 V			±0.25		±2.5		±2.5	µA
I _{CC}	V _I = V _{CC} or GND, I _O = 0	5.5 V			4		40		40	µA
C _i	V _I = V _{CC} or GND	5 V		2	10				10	pF
C _o	V _O = V _{CC} or GND	5 V		3						pF

* On products compliant to MIL-PRF-38535, this parameter is not production tested at V_{CC} = 0 V.

switching characteristics over recommended operating free-air temperature range,
V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			SN54AHC16541		SN74AHC16541		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	A	Y	C _L = 15 pF		5**	8.4**	1**	10**	1	10	ns
t _{PHL}					5**	8.4**	1**	10**	1	10	
t _{PZH}	$\overline{\text{OE}}$	Y	C _L = 15 pF		6**	10.6**	1**	12.5**	1	12.5	ns
t _{PZL}					6**	10.6**	1**	12.5**	1	12.5	
t _{PHZ}	$\overline{\text{OE}}$	Y	C _L = 15 pF		7**	11.5**	1**	12.5**	1	12.5	ns
t _{PLZ}					7**	11.5**	1**	12.5**	1	12.5	
t _{PLH}	A	Y	C _L = 50 pF		7.5	11.9	1	13.5	1	13.5	ns
t _{PHL}					7.5	11.9	1	13.5	1	13.5	
t _{PZH}	$\overline{\text{OE}}$	Y	C _L = 50 pF		8	14.1	1	16	1	16	ns
t _{PZL}					8	14.1	1	16	1	16	
t _{PHZ}	$\overline{\text{OE}}$	Y	C _L = 50 pF		9	14	1	16	1	16	ns
t _{PLZ}					9	14	1	16	1	16	
t _{sk(o)}			C _L = 50 pF			1.5***				1.5	ns

** On products compliant to MIL-PRF-38535, this parameter is not production tested.

*** On products compliant to MIL-PRF-38535, this parameter does not apply.

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switching characteristics over recommended operating free-air temperature range,
 $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	$T_A = 25^\circ\text{C}$			SN54AHC16541		SN74AHC16541		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	Y	$C_L = 15\text{ pF}$	3.5*	6*		1*	7*	1	6.5	ns
t_{PHL}				3.5*	6*		1*	7*	1	6.5	
t_{PZH}	\overline{OE}	Y	$C_L = 15\text{ pF}$	4.7*	7.3*		1*	8.5*	1	8.5	ns
t_{PZL}				4.7*	7.3*		1*	8.5*	1	8.5	
t_{PHZ}	\overline{OE}	Y	$C_L = 15\text{ pF}$	5*	7.2*		1*	8.5*	1	8.5	ns
t_{PLZ}				5*	7.2*		1*	8.5*	1	8.5	
t_{PLH}	A	Y	$C_L = 50\text{ pF}$	5	8		1	9	1	8.5	ns
t_{PHL}				5	8		1	9	1	8.5	
t_{PZH}	\overline{OE}	Y	$C_L = 50\text{ pF}$	6.2	9.3		1	10.5	1	10.5	ns
t_{PZL}				6.2	9.3		1	10.5	1	10.5	
t_{PHZ}	\overline{OE}	Y	$C_L = 50\text{ pF}$	6	9.2		1	10.5	1	10.5	ns
t_{PLZ}				6	9.2		1	10.5	1	10.5	
$t_{sk(o)}$			$C_L = 50\text{ pF}$		1**					1	ns

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

** On products compliant to MIL-PRF-38535, this parameter does not apply.

noise characteristics, $V_{CC} = 5\text{ V}$, $C_L = 50\text{ pF}$, $T_A = 25^\circ\text{C}$ (see Note 4)

PARAMETER		SN74AHC16541			UNIT
		MIN	TYP	MAX	
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}		0.7		V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}		–0.3		V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}		4.7		V
$V_{IH(D)}$	High-level dynamic input voltage	3.5			V
$V_{IL(D)}$	Low-level dynamic input voltage			1.5	V

NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load, $f = 1\text{ MHz}$	12	pF

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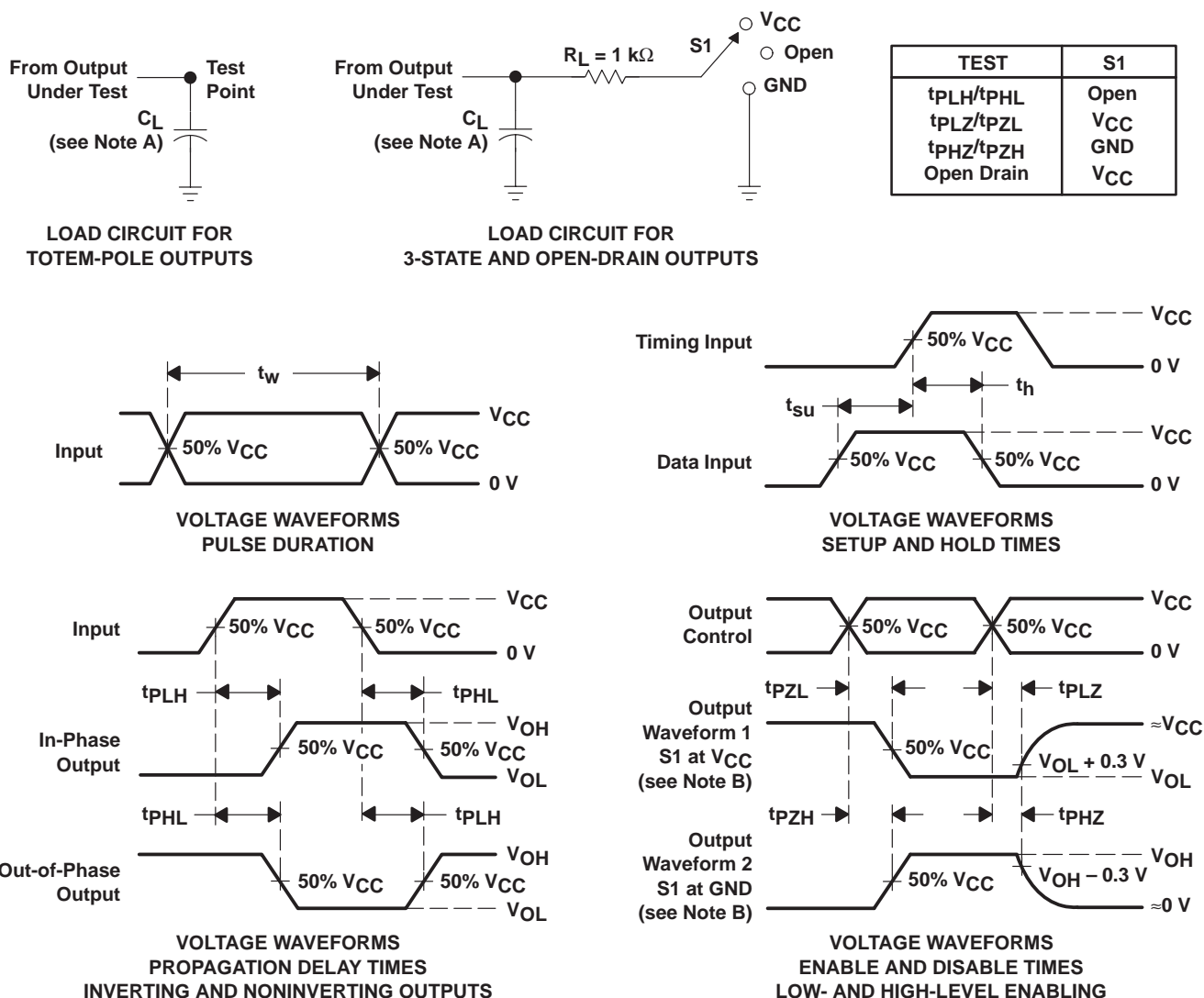
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PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 3\text{ ns}$, $t_f \leq 3\text{ ns}$.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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